## A tom ic-scale surface dem ixing in a eutectic liquid B iSn alloy

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R esonant x-ray re ectivity of the surface of the liquid phase of the  $Bi_{43}Sn_{57}$  eutectic alloy reveals atom ic-scale dem ixing extending over three near-surface atom ic layers. Due to the absence of underlying atom ic lattice which typically de nes adsorption in crystalline alloys, studies of adsorption in liquid alloys provide unique insight on interatom ic interactions at the surface. The observed com position m odulation could be accounted for quantitatively by the D efay-P rigogine and Strohl-K ing m ultilayer extensions of the single-layer G ibbs m odel, revealing a near-surface dom ination of the attractive B iSn interaction over the entropy.

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The widely-accepted Gibbs adsorption rule [1] predicts the surface segregation of the lower surface energy component of a binary mixture. Liquid metals are ideal systems for studying G ibbs adsorption due to the nearly spherical shape of interacting particles, relative sim plicity of the short-range interactions and the availability of bulk therm odynam ic data form any binary albys. W hile certain aspects of G ibbs theory can be tested through m acroscopic m easurem ents of surface tension or adsorption isotherms, very few direct measurements of the atom ic-scale composition pro les of the liquid-vapor interface were reported [2, 3, 4]. In addition to fundam ental questions related to surface therm odynam ics of binary liquids, B iSn-based alloys have been widely studied as substitutes for Pb-based low-melting solders [5]. Thus, understanding their wetting, spreading, alloying, reactivity and other surface-related properties is of great practical in portance. M oreover, interfacial phenom ena dom inate the properties of the increasingly important class of nanoscale m aterials, as dem onstrated recently in studies of the liquid-solid phase stability of nanom etersized B iSn particles [6].

Synchrotron-based x-ray re ectivity (XR) can measure the surface-norm al density prole of a liquid with Angstrom-scale resolution. Over the last decade XR revealed the long-predicted surface-induced atom ic layering at the liquid-vapor interface for a number of elem ental liquid metals [7, 8, 9, 10, 11]. Resonant XR near an absorption edge resolved the density prole of each component in G aIn [2], HgAu [3] and B iIn [4] liquid binary alloys. The enhancement of the concentration of the low-surface-tension component was invariably found to be con ned to the topm ost surface monolayer, with subsequent layers having the composition of the bulk, in accord with the simplest, and widely used, interpretation of the G ibbs rule. By contrast, we nd here an atom ic-scale phase separation extending over at least three atom ic layers. This is unexpected, considering the near-perfectsolution nature of the  $B_{4_3}Sn_{57}$  alloy in the bulk [12, 13].

A liquid  $\rm B\,i_{43}Sn_{57}$  sam ple (99.99% purity, A lfa Aesar) was prepared under UHV conditions (P < 10  $^9$  Torr). A tom ically clean liquid surfaces were obtained by mechanical scraping and Ar<sup>+</sup> ion sputtering, as described previously [10, 14, 15]. Measurements were done using the liquid surface di ractom eter at the Chem M atCARS beam line, A dvanced Photon Source, A rgonne N ational Laboratory at a sam ple tem perature of T = 142 C, 4 C above the Bi<sub>43</sub>Sn<sub>57</sub> alloy's eutectic tem perature,  $T_e=138$  C.

The relected intensity fraction,  $R(q_z)$ , of an x-ray beam impinging on a structured liquid surface at a grazing angle , is given by the Born approximation as:

$$R(q_z) = R_F(q_z) j(q_z) f CW(q_z)$$
 (1)

where  $q_z = (4 = ) \sin$ , is the x-ray wavelength,  $R_F(q_z)$  is the Fresnel XR of an ideally abrupt and at surface, CW  $(q_z)$  is due to therm alsurface capillary waves [9, 10], and the surface's structure factor is [16]:

$$(q_z) = \frac{1}{1} \int_{1}^{Z} dz \frac{dh(z)i}{dz} \exp(\{q_z z\});$$
 (2)

Here z is the surface-norm alaxis,  $_1$  and (z) are the bulk and surface electron densities, respectively, and h:: denotes surface-parallel averaging. As R<sub>F</sub> is a universal function depending only on the known critical angle for total external re ection, and CW (q<sub>z</sub>) is known accurately from capillary wave theory, the intrinsic density pro le, h (z)i, is obtained by computer thing the measured R (q<sub>z</sub>) by a physically motivated model described below [10].

The (forward) atom ic scattering factor of a Z -electron atom varies with energy as [16]:  $Z^0 = Z + f^0(E)$  if (E), where  $f^0(E)$  and  $f^{(0)}(E) = (E) = (4)$ , are the real and

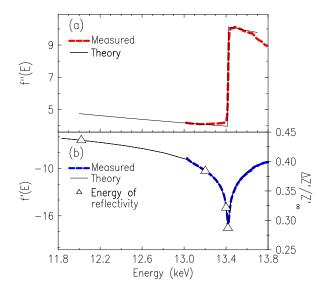


FIG.1: Dispersion corrections (a)  $f^0(E)$  and (b)  $f^{00}(E)$  of Binear the L3 absorption edge at  $E_{\rm L3}$  = 13:418 keV.The right scale of (b) is the electron density contrast  $Z^{0}=Z^{0}_{1}$  =  $(Z^{0}_{\rm Bi} \ Z^{0}_{\rm Sn})=Z^{0}_{1}$ .

in aginary parts of the dispersion correction, and (E) is the photoelectric absorption  $\infty e$  cient.

The e ect of  $f^{(0)}$  on the analysis can be neglected and the changes in  $f^0$  are signi cant only near an absorption edge. Fig. 1(a) shows  $f^{(0)}(E)$  near the BiL3 edge as obtained from an absorption measurement in a Bi foil. Fig. 1(b) is the corresponding  $f^0(E)$ , calculated from  $f^{(0)}(E)$  using the K ram ers-K ronig relation [17]. Both agree wellw ith theory [18, 19]. The composition dependence of h(z) i was obtained by tting the measured X R by the distorted crystal (DC) model for a layered liquid surface [7, 8]:

$$\frac{h(z)i}{1} = \frac{X^{i}}{p} = \frac{e^{(z - nd)^{2} = \frac{2}{n}}}{p - 2} + \frac{Z^{0}_{Bi} - Z^{0}_{Sn}}{Z^{0}_{1}} + \frac{Z^{0}_{Bi} - Z^{0}_{Sn}}{Z^{0}_{1}} + \frac{C^{0}_{R}}{c}$$
(3)

The progressive increase in the Gaussian width param eter  $n^2 = 0^2 + (n - 1)^{-2}$  with increasing layer num ber n describes the layering amplitude's decay below the surface [8]. The layer spacing d is kept constant in this m odel due to sim ilarity in size between Biand Sn atom s. The bulk's average e ective electron number per atom is  $Z_{1}^{0} = xZ_{Bi}^{0} + (1 x)Z_{Sn}^{0}$ , and  $n = x_{n}^{0}$ x is difference in the Bi fraction between the n-th layer,  $x_n^0$ , and the bulk, x. The corresponding atom ic densities,  $c_n$  and  $c_r$  are determined from the atom ic volumes  $v_{B_1}$ and  $v_{Sn}$ :  $c_n x_n^0 v_{Bi} + c_n$  (1)  $x_{h}^{0}$ ) $v_{Sn} = 1$ . The contrast,  $\rm Z^0_{S\,n}\,){=}Z^{\,0}_{\,1}$  , varies strongly near the edge due to (Z<sup>0</sup><sub>Bi</sub> the variation of  $Z_{Bi}^{0}$ : from 0:43 at E = 12.00 keV to 0:27 at E = 13.418 keV (right axis in Fig. 1). This is the basis for the resonant X R m ethod w hich allows to separate out the density pro les of the two species [4, 15].

Fig. 2 shows Fresnel-norm alized XRs R ( $q_z$ )=R<sub>F</sub> ( $q_z$ )

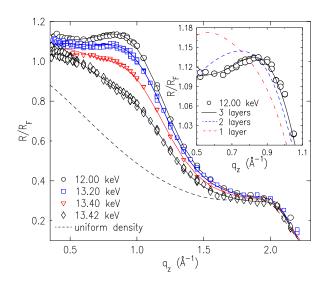


FIG.2: XR m easured at the indicated energies, with ts by the three-layer m odel (lines). The dashed line is the XR of a uniform -composition surface. Inset: The E=12.00 keV m easured R=R<sub>F</sub> with ts by the three models discussed in the text (lines). Error bars are sm aller than the symbols' size.

m easured near the BiL3 edge at the four energies marked by triangles in Fig. 1(b). The dashed line is calculated from the DC model for a layered interface assuming a uniform composition ( $_n = 0$ ). The strong enhancement of the measured R ( $q_z$ )=R<sub>F</sub> ( $q_z$ ) over this line, evidenced by the peak at  $q_z$  ' 1:0 A <sup>1</sup>, and the strong energydependence of the low  $-q_z$  re ectivity, clearly indicate a signi cant surface segregation of Bi, and its variation with z.

Three ts of the data by the DC model, Eq. 3, were carried out, assuming that only one ( $_1 \notin 0$ ,  $_n _2 = 0$ ), two ( $_{1;2} \notin 0$ ,  $_n _3 = 0$ ), or three ( $_{1;2;3} \notin 0$ ,  $_n _4 = 0$ ) surface layers deviate from the bulk composition. All ts employed d = 2:90 A,  $_0 = 0:30$  A and - = 0:57 A, derived from the energy-independent position, shape and intensity of the layering peak at  $q_z = 2:0$  A  $^1$ . The measured R ( $q_z$ )=R<sub>F</sub> ( $q_z$ ) of all four energies were tted simultaneously, using the experimentally determined f<sup>0</sup>(E).

Fig.2 exhibits an excellent agreem ent of the three-layer model (solid lines) with the measurements, but a very poor agreem ent for the one-and two-layerm odels (inset). Table I lists the best-t values of  $x_n^0$  and  $\frac{F}{n}^{it} = x_n^0$ Х and the corresponding 95% non-linear con dence intervals Y  $(x_n^0\,)$  and Y (  $_n^{\rm F\ it})$  determ ined from a six-parameter support plane analysis [20]. The most striking result is the non-monotonic deviation n of Bifrom the 43% bulk value, showing an enhanced com position of 96% and 53% in the rst and third layers, and depletion down to 25% in the second layer (see Fig. 3). Beyond the third layer entropy e ects dom inate the G ibbs adsorption and the layer and bulk concentrations can not be distinguished. W hile dem ixing has not been previously reported in liquid alloys, sim ilar decaying oscillatory composition pro-

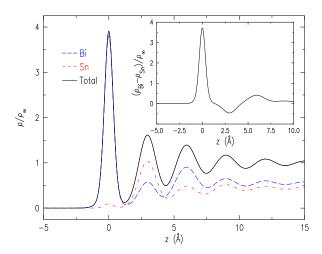


FIG. 3: Electron density pro les as derived from the ts to the re ectivities shown in Fig. 2. Inset: the bulk-normalized di erences in electron density of Biand Sn, (Bi Sn) = 1.

les were discovered in several crystalline alloys such as  $Cu_3Au$  [21]. However, the properties, form ation mechanism, and strong temperature dependence of the composition modulations in  $Cu_3Au$  alloys were found to be intim ately related to, and largely dom inated by, the long-range fcc order in the bulk crystal, and the severe packing strains resulting from the big m ism atch in the atom ic diameter of the two components. As none of these exist in our liquid alloy, surface-induced segregation and the G ibbs rule can be studied in a pure short-range-order interaction context, free from the complicating in uence, or even dom inance, of other e ects. We now compare our experimental observations with theory.

Guggenheim's [22] application of G ibbs theory [1] to regular solutions assumes the surface segregation to be restricted to a single surface monolayer. Assuming p nearest neighbors for each bulk atom in a layered lattice model, lp are within, and mp are in the adjacent, layers. For a close-packed lattice, for example, p = 12, l = 0.5 and m = 0.25. The surface tension of the regular solution,  $_{AB}$ , follows from those of the pure components,  $_{A}$  and  $_{B}$ , as [22]:

$${}_{AB} = {}_{B} + \frac{kT}{a_{B}} \ln \frac{1}{1} \frac{x^{0}}{x} + \frac{!}{a_{B}} [1x^{02} \quad (1+m)x^{2}] \quad (4)$$
$$= {}_{A} + \frac{kT}{a_{A}} \ln \frac{x^{0}}{x} + \frac{!}{a_{A}} [1(1 \quad x^{0})^{2} \quad (1+m)(1 \quad x^{2})];$$

Here, x and (1 x) are the bulk concentrations of atom s A (B i) and B (Sn), while  $x^0 \in x$  and (1  $x^0$ ) are the corresponding surface concentrations,  $a_A$  and  $a_B$  are the two atom ic areas, and  $! = 2!_{AB} !_{AA} !_{BB}$  is the interaction parameter, de ned by the A-B, A-A and B-B atom ic interaction energies. Extrapolated down to T = 142 C,  $_{Bi} = 398 \text{ m N/m}$  and  $_{Sn} = 567 \text{ m N/m}$ , while  $a_{Bi}$  and  $a_{Sn}$  are calculated from the atom ic radii  $r_{Bi} = 1:70 \text{ A}$ and  $r_{Sn} = 1:62 \text{ A}$  assuming hexagonal close packing [23].

n	х <sup>0</sup> (В і)	Y (x <sup>0</sup> <sub>n</sub> )	F it n	Y ( <sup>F it</sup> )	D P n	SK n
1	0.96	[0.94,0.99]	0.53	[0.51,0.56]	0.47	0.51
2	0.25	[0.18,0.27]	-0.18	[+0.25,-0.16]	-0.23	-0.25
3	0.53	[0.50,0.56]	0.10	[0.07,0.13]	0.12	0.05
4	0.43	-	0	-	-0.06	-0.01

TABLE I: Density model parameters  $x_n^0$  and  $r_n^{F \text{ it}} = x_n^0 \quad x$ , and con dence intervals Y ( $x_n^0$ ) and Y ( $r_n^{F \text{ it}}$ ) obtained from the three-layer model ts compared to theoretical  $n_n^{D P}$  and  $n_n^{S K}$  derived from the D efay-P rigogine and Strohl-K ing models.

Treating  $B_{4_3}Sn_{5_7}$  as a perfect solution (!=kT = 0), the Gibbs theorem , Eq. 4, yields  $_{AB} = 444 \text{ mN/m}$  and  $x^0 = 0.904$ , below the experimental value  $x_1^0$  (Bi) in Table I. However, assuming a regular solution behavior with !=kT = 1 yields  $_{AB} = 432$  mN/m, and  $x^0 = 0.941$ , which agrees very well with the experim entally derived  $x_1^0$  (Bi) in Table I. Both <sub>AB</sub> agree well with experiment and theory [24]. Note that  $_{AB}$  and  $x^0$  are only weakly dependent on !=kT due prim arily to the logarithm ic functional behavior and large surface tension di erence of the two components, a<sub>Sn Sn</sub> ₿і Ві 2 kT. This introduces a large uncertainty of !=kT calculated from measurem ents of surface tension or surfacem onolayer com position. Resonant XR measurements of sub-surface layer composition therefore present a unique opportunity to probe the nature of atom ic interactions at the surface.

In spite of the good agreement above, con ning the surface excess to a single monolayer is correct for perfect solutions only, but not for our case of a regular solution, as D efay and P rigogine [25] point out. They provide a correction for regular solutions, where the surface excess extends over two layers, the  $_{AB}$  values above do not change signi cantly and the layers'  $_{n}$  are related by:

$$\ln \frac{1+_{2}=x}{1_{2}=(1-x)} \quad \frac{2!}{kT} = \frac{2!m}{kT} (_{1} - 2_{2}) = 0: (5)$$

Expanding Eq.5 to rst order in  $_2$ :

$$_{2} = \frac{2! m x (1 x)_{1}}{kT 2! lx (1 x)};$$
 (6)

For nearly perfect solutions (!=kT)1) Eq. 5 yields a negligible  $_2: 0 < _2$ 1. For !=kT & 1, however,  $_2$  and  $_1$  are of opposite signs and  $j_2 jm ay be$ com e com parable to  $j_1 j_1$ . This prediction is qualitatively consistent with the dem ixing observed here. For exam -1, Eq. 6 can be simplied further: ple, when !=kT  $(m = 1)_1$ . For  $Bi_{43}Sn_{57}$ , m = 1 0:5 and the G ibbspredicted  $x_1^0 = 0.90$  (or  $_1 = 0.47$ ) yields  $_2 = 0.23$ ,  $_3 = 0.12$  and  $_4 = 0.06$  [26]. These values, shown as  ${}_{n}^{D\ P}$  in Table I, agree well with  ${}_{n}^{F\ it}$  obtained from the three-layer model ts. The smallest value of the interaction parameter != kT for which satisfactory agreement with the Defay-Prigogine model could be obtained (by treating m as an adjustable parameter) is !=kT = 23.

Strohl and K ing [27] suggest a multilayer, multicom ponent model, where no expansion is used, and  $x_n^0$  are obtained iteratively, until convergence to a self-consistent composition prole is reached. A good agreement of this theory with our B iSn measurements is obtained when !=kT = 1:0 1:7. Typical  $_n^{SK}$  values are listed in Table I. As observed, the Strohl-K ing model provides composition proles very similar to those of the D efay-P rigogine model, albeit with slightly dilerent n values, thus supporting our overall conclusions.

Theoretically, ! and the enthalpy of mixing, H m, are related by  $! = H_m = [x (1)]$ x)]. In practice, how ever, bulk therm odynam ic quantities were often found to yield inaccurate values for surface quantities. For exam ple, organic [28] and metallic [29] mixtures exhibit signi cant disagreem ents between ! values derived em pirically from surface tension measurements and from bulk calorim etry. For BiSn, reported values of H m range from endotherm ic values of 80 to 140 J/m ol [12] to an exotherm ic value of -180 J/m ol [13]. These values lead to j! = kT j < 0.2, i.e. an alm ost perfect solution, and an insignicant  $j_2 j < 0.01$ . On the other hand, the value of!=kT 10 that we previously found necessary to account for the observed 35% Bi concentration enhancem ent at the surface m on olayer at the B iIn eutectic is of the same order of magnitude as the value we nd necessary to account for the present observation of surface sequence in B is n, ! = kT1:0 2:3. Unfortunately we do not have an explanation for the origin of the discrepancy in the values of !=kT and this suggests an urgent need for both further theoretical studies of surface dem ixing as well as experim ental investigations of sim ilare ects in other binary alloys. In particular, the BiSn system appears to be the only liquid alloy for which clear evidence for multilayer surface dem ixing has been found. The case for new studies is strongly reinforced by the existence of a growing class of surface-induced ordering phenom ena that have been observed in m etallic liquids. In addition to the surface dem ixing reported here, these include layering [7, 8, 9, 10, 11], relaxation [11], segregation [2, 3, 4, 30], wetting transitions [14, 31], and surface freezing [32]. Finally, there is a basic unresolved question of whether the surfaces of liquid metals are fundamentally di erent from those of non-m etallic liquids [33].

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